NSN 5961-01-575-9865

Diode Semiconductor Device - Page 1 of 1



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Voltage Rating In Volts Per Characteristic:

375.0 emitter to collector voltage, floating potential, dc with base biased in reverse direction with respect to the collector not applicable and 400.0 reach through voltage not applicable

Capacitance Rating In Picofarads:

0.1

Maximum Operating Tempurature Per Measurement Point:

175.0 inlet swivel degrees fahrenheit

Product Name:

Beam lead schottky dc tested diode

Special Features:

Platinum tri-metal system; silicon nitride passivated; low barrier; packaged 20 units; 20 ohm maximum dynamic reistance; suited for stripline or microline circuits; dc tested; 4 volt min breakdown

Precious Material And Location:

Leads gold

Precious Material:

Gold

Shelf Life: N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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